Ehipsmall

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General Description

The MAX8809A/MAX8810A synchronous, 2-/3-/4 phase, step-down, current-mode controllers with integrated dual-phase MOSFET drivers provide flexible solutions that fully comply with Intel[®] VRD11/VRD10 and AMD K8 Rev F CPU core supplies. The flexible design supplies load currents up to 150A for low-voltage CPU core power requirements.

A tri-state SEL input is available to configure the VID logic for either the Intel VRD11/VRD10 or AMD K8 Rev F applications. An enable input (EN) is available to disable the IC. True-differential remote output-voltage sensing enables precise regulation at the load by eliminating the effects of trace impedance in the output and return paths. A high-accuracy DAC combined with precision current-sense amplifiers and droop control enable the MAX8809A/MAX8810A to meet the most stringent tolerance requirements of new-generation high-current CPUs. These ICs use either integral or voltage-positioning feedback control to achieve high output-voltage accuracy.

The COMP input allows for either positive or negative voltage offsets from the VID code voltage. A powergood signal (VRREADY) is provided for startup sequencing and fault annunciation. The SS/OVP pin enables the programming of the soft-start period, and provides an indication of an overvoltage condition. A soft-stop feature prevents negative voltage spikes on the output at turn-off, eliminating the need for an external Schottky clamp diode.

The MAX8809A/MAX8810A incorporate a proprietary "rapid active average" current-mode control scheme for fast and accurate transient-response performance, as well as precise load current sharing. Either the inductor DCR or a resistive current-sensing element is used for current sensing. When used with DCR sensing, rapid active current averaging (RA2) eliminates the tolerance effects of the inductance and associated current-sensing components, providing superior phase current matching, accurate current limit, and precise load-line.

The MAX8809A operates as a single-chip, 2-phase solution with integrated drivers. It also provides a 3rdphase PWM output and easily supports 3-phase design by adding the MAX8552 high-performance driver. The MAX8810A enables up to 4-phase designs by adding the MAX8523 high-performance dual driver for a compact 2-chip solution.

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Features

- ♦ **VRD11/VRD10 and K8 Rev F Compliant**
- ♦ **±0.35% Initial Output Voltage Accuracy**
- ♦ **Dual Integrated Drivers with Integrated Bootstrap Diodes**

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- ♦ **Up to 26V Input Voltage**
- ♦ **Adaptive Shoot-Through Protection**
- ♦ **Soft-Start, Soft-Stop, VRREADY Output**
- ♦ **Fast Load Transient Response**
- ♦ **Individual Phase, Fully Temperature-Compensated Cycle-by-Cycle Average Current Limit**
- ♦ **Current Foldback at Short Circuit**
- ♦ **Voltage Positioning or Integral Feedback**
- ♦ **Differential Remote Voltage Sensing**
- ♦ **Programmable Positive and Negative Offset Voltages**
- ♦ **150kHz to 1.2MHz Switching Frequency per Phase**
- ♦ **NTC-Based, Temperature-Independent Load Line**
- ♦ **Precise Phase Current Sharing**
- ♦ **Programmable Thermal-Monitoring Output (VRHOT)**
- ♦ **6A Peak MOSFET Drivers**
- ♦ **0.3**Ω**/0.85**Ω **Low-Side, 0.8**Ω**/1.1**Ω **High-Side Drivers (typ)**
- ♦ **40-Pin and 48-Pin Thin QFN Packages**

Applications

Desktop PCs Servers, Workstations Desknote and LCD PCs Voltage-Regulator Modules

Ordering Information

+Denotes lead-free package.

Note: All parts are specified in the -40°C to +85°C extended temperature range.

Pin Configurations appear at end of data sheet.

__ *Maxim Integrated Products* **1**

For pricing delivery, and ordering information please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

REF, COMP, SS/OVP, OSC, NTC, VRTSET,

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{VL} = V_{BST} = 6.5V, V_{CC} = V_{EN} = 5V, V_{ILIM} = 1.5V, VID = SEL = REF = BUF = unconnected, V_{COMP} = V_{RS} = 1.0V, RVRREADY = 1.0V$ 5k Ω pullup to 5V, Rss/OVP = 12k Ω to GND, R_{NTC} = 10k Ω to GND, fsw = 300kHz, RvRTSET = 118k Ω to GND, V_{CS_+} = V_{CS_-} = 1V, PWM_ = unconnected, RVRHOT = 249Ω pullup to 1.05V, VGND = VPGND_ = VLX_ = VRS- = 0V, DL_ = DH_ = unconnected, **TA = 0**°**C to +85°C**. Typical values are at $T_A = +25$ °C, unless otherwise noted.)

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{VL} = V_{BST} = 6.5V$, $V_{CC} = V_{EN} = 5V$, $V_{ILIM} = 1.5V$, $VID = SEL = REF = BUF = unconnected$, $V_{COMP} = V_{RS+} = 1.0V$, $R_{VRREADY} = V_{RS+} = 1.0V$ 5kΩ pullup to 5V, Rss/OVP = 12kΩ to GND, RNTC = 10kΩ to GND, fsw = 300kHz, RVRTSET = 118kΩ to GND, VCS + = VCS - = 1V, PWM_ = unconnected, RVRHOT = 249Ω pullup to 1.05V, VGND = VPGND_ = VLX_ = VRS- = 0V, DL_ = DH_ = unconnected, **TA = 0**°**C to +85°C**. Typical values are at $T_A = +25$ °C, unless otherwise noted.)

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ELECTRICAL CHARACTERISTICS (continued)

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ELECTRICAL CHARACTERISTICS (continued)

 $(V_{VL} = V_{BST} = 6.5V, V_{CC} = V_{EN} = 5V, V_{ILIM} = 1.5V, VID = SEL = REF = BUF = unconnected, V_{COMP} = V_{RS+} = 1.0V, RV_{RREADY} = 1.0V$ 5kΩ pullup to 5V, Rss/OVP = 12kΩ = RNTC = 10kΩ to GND, fsw = 300kHz, RVRTSET = 50kΩ to GND, VCS + = VCS - = 1V, PWM_ = unconnected, $R_{VPHOT} = 249Ω$ pullup to 1.05V, $V_{GND} = V_{PGND} = V_{LX} = V_{RS} = 0V$, $DL = DH =$ unconnected, $T_A = -40°C$ to **+85**°**C**.) (Note 2)

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{VL} = V_{BST} = 6.5V, V_{CC} = V_{FN} = 5V, V_{ILIM} = 1.5V, VID = SEL = REF = BUF = unconnected, V_{COMP} = V_{RS} = 1.0V, R_{VRREADY} = 0.0048$ $5k\Omega$ pullup to 5V, Rss/OVP = 12k Ω = RNTC = 10k Ω to GND, fsw = 300kHz, RVRTSET = 50k Ω to GND, V_{CS_+} = V_{CS_-} = 1V, PWM_ = unconnected, R_{VRHOT} = 249Ω pullup to 1.05V, V_{GND} = V_{PGND_1} = V_{LX_1} = V_{RS_1} = 0V, DL_1 = DH_n = unconnected, T_A = -40°C to **+85**°**C**.) (Note 2)

Note 1: V_{DAC} refers to the internal voltage set by the VID code.

Note 2: Specifications to -40°C are guaranteed by design and characterization.

Typical Operating Characteristics

(Circuit of Figure 14, V_{IN} = 12V, V_{OUT} = 1.35V, I_{OUT_MAX} = 115A, R_O = 1m Ω , f_{SW} = 200kHz, V_{CC} = 5V, V_{VL} = 6.5V, T_A = +25°C, unless otherwise noted.)

MAX8809A/MAX8810A **A01887AM/A2887AM**

Typical Operating Characteristics (continued)

(Circuit of Figure 14, V_{IN} = 12V, V_{OUT} = 1.35V, I_{OUT_MAX} = 115A, R_O = 1m Ω , fsw = 200kHz, V_{CC} = 5V, V_{VL} = 6.5V, T_A = +25°C, unless otherwise noted.)

SHUTDOWN WAVEFORMS AT FULL LOAD

180

SHORT-CIRCUIT AND RECOVERY WAVEFORMS

REFERENCE VOLTAGE vs. AMBIENT TEMPERATURE

Typical Operating Characteristics (continued)

(Circuit of Figure 14, V_{IN} = 12V, V_{OUT} = 1.35V, I_{OUT} $_{MAX}$ = 115A, R_O = 1mΩ, f_{SW} = 200kHz, V_{CC} = 5V, V_{VL} = 6.5V, T_A = +25°C, unless otherwise noted.)

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MAX8809A/MAX8810A

A01887AM/A2887AM

Typical Operating Characteristics (continued)

(Circuit of Figure 14, V_{IN} = 12V, V_{OUT} = 1.35V, I_{OUT_MAX} = 115A, R_O = 1mΩ, f_{SW} = 200kHz, V_{CC} = 5V, V_{VL} = 6.5V, T_A = +25°C, unless otherwise noted.)

Typical Operating Characteristics (continued)

(Circuit of Figure 14, V_{IN} = 12V, V_{OUT} = 1.35V, I_{OUT_MAX} = 115A, R_O = 1m Ω , f_{SW} = 200kHz, V_{CC} = 5V, V_{VL} = 6.5V, T_A = +25°C, unless otherwise noted.)

Pin Description

Pin Description (continued)

Pin Description (continued)

Pin Description (continued)

Figure 1. Block Diagram

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MAX8809A/MAX8810A

MAX8809A/MAX8810A

Figure 2. Driver Timing Diagram

Detailed Description

The MAX8809A/MAX8810A synchronous, 2-/3-/4 phase, step-down, current-mode controllers with integrated dual-phase MOSFET drivers provide flexible solutions that fully comply with Intel VRD11/VRD10 and AMD K8 Rev F CPU core supplies. The flexible design supplies load currents of up to 150A for low-voltage CPU core power supplies.

The MAX8809A is suitable for 2- or 3-phase core supply applications. With an integrated dual-MOSFET driver, the MAX8809A offers a single-chip IC solution for dual-phase core supplies. Together with the MAX8552, a high-performance single-phase MOSFET driver, the MAX8809A also supports 3-phase core supplies. Similarly, the MAX8810A features a single IC solution for dual-phase core supplies. It also features two-IC solutions for 3- or 4-phase core supplies by adding a single MOSFET driver (MAX8552) or a dual-MOSFET driver (MAX8523).

Both the MAX8809A and MAX8810A fully comply with Intel VRD11, Extended VRD10, and the AMD K8 Rev F VID codes. The SEL input allows the user to select the architecture specifications.

Clock Frequency (OSC)

An external resistor, Rosc, from OSC to GND sets the internal clock frequency of the MAX8809A/MAX8810A. A 1% resistor is recommended to maintain good frequency accuracy. The internal clock frequency sets the per-phase switching frequency. The selection of switching frequency per phase is influenced by factors such as the switching speed of the MOSFETs, the inductor's core material, different types of input and output capacitors, and the available board space. Once the perphase switching frequency is selected, the internal clock frequency is determined using the procedure in the Setting the Switching Frequency section.

Voltage Reference (REF)

A precision 2V reference is provided by the MAX8809A/ MAX8810A at the REF output. REF is capable of sinking and sourcing up to 500µA for external loads. Connect a 0.1µF to 1µF ceramic capacitor from REF to GND. Internal REFOK circuitry monitors the reference voltage. The reference voltage must be above the REFOK threshold of 1.84V to activate the controller. The controller is disabled if the reference voltage falls below 1.74V.

Output Current Sensing (CS +, CS -)

The output current of each phase is sensed differentially. A low-offset-voltage, differential-current amplifier (30V/V) at each phase allows low-resistance currentsense resistors to be used to minimize power dissipation. Sensing the current at the output of each phase offers advantages including less noise sensitivity, more accurate current sharing between phases, and the flexibility of using either a current-sense resistor or the DC resistance of the output inductor.

Using the DC resistance, R_{DC} , of the output inductor (Figure 3) allows higher efficiency. In this configuration, the initial tolerance and temperature coefficient of R_{DC} must be accounted for in the output-voltage droop-error budget. The temperature coefficient can be compensated; see the Load-Line Independent Inductor DC Resistance Temperature Compensation section for more details. An RC-filtering network is needed to extract the current information from the output inductor. The time constant of the RC network is calculated as follows:

$$
R1 \times C1 = \frac{L}{R_{DC}}
$$

where L is the inductance of the output inductor. For 20A or higher current-per-phase applications, the DC resistance of commercially available inductors is approximately 1mΩ. To minimize current-sense error due to the bias current at the current-sense inputs, choose R1 less than $2kΩ$. Determine the value for C1 as:

Figure 3. Inductor R_{DC} Current Sense

$$
C1 = \frac{L}{(R_{DC} \times R1)}
$$

Select a 1% resistor for R1. For mainstream PCs 20% tolerance is recommended for C1, and for performance PCs 10% tolerance should be considered. If using an inductor with R_{DC} greater than 1mΩ, a resistor (R2) may be necessary to divide down the voltage across CS_+ and CS_-. The maximum average signal present at the input of the current-sense amplifier should not exceed 85mV.

When a current-sense resistor is used for more accurate current sharing and load-line, a similar RC-filtering circuit is recommended to cancel the equivalent series inductance of the current-sense resistor, as shown in Figure 4. Again, select R2 less than 2kΩ, and C2 is determined by the following equation:

$$
C2 = \frac{ESL}{(R_S \times R2)}
$$

where ESL is the equivalent series inductance of the current-sense resistor and RS is the value of the current-sense resistor. For example, a 1mΩ, 2025 package sense resistor has an ESL of 1.6nH. If using an RS greater than 1m Ω , a resistor (R2) may be necessary to divide down the voltage across CS_+ and CS_-. The maximum average signal present at the input of the current-sense amplifier should not exceed 85mV.

Output Current Limit and Short-Circuit Protection (ILIM)

The MAX8809A/MAX8810A feature a precise average output current limit on a cycle-by-cycle basis using Maxim's proprietary RA2 technology. The current-limit scheme is insensitive to input-voltage variation, the inductor tolerance, and the tolerance of the currentsense capacitor, permitting the use of low-cost components to reduce total BOM cost. Furthermore, the current limit is fully temperature compensated resulting

Figure 4. Resistor Current Sense

in a constant output current limit over the entire operational temperature range. This eliminates the need to oversize MOSFETs and inductors to compensate for thermal effects. Connecting ILIM to V_{CC} programs the default current-limit threshold. To select a different current-limit threshold, connect a resistor-divider from REF to GND with ILIM connected to the center tap. The voltage at ILIM is proportional to the current-limit threshold. See the Setting the Current-Limit section for more details.

The current-limit circuitry terminates the DH_ on-time immediately when the current-sense voltage (V_{CS+} -V_{CS}-) exceeds the current-limit threshold, allowing the output inductor current to ramp down. At the next switching cycle, the PWM pulse is skipped if the output inductor current is still above the current-limit threshold. Otherwise, the new cycle initiates as normal.

The MAX8809A/MAX8810A offer foldback-current protection under soft-start and overload conditions. This feature allows the VRM to safely operate under shortcircuit conditions and to automatically recover once the short-circuit condition is removed. If the output voltage falls below the VRREADY threshold during an overcurrent event, the foldback current-limit circuitry sets the current-limit threshold to half the user-selected value.

Output Differential Sensing (RS+, RS-)

The MAX8809A/MAX8810A feature differential outputvoltage sensing to achieve the highest possible output accuracy. This allows the controllers to sense the actual voltage at the load, so the controller can compensate for losses in the power output and ground lines. Traces from the load point back to RS+ and RS- should be routed close to each other and as far away as possible

Figure 5. Recommended Filtering for Output-Voltage Remote Sensing

from noise sources (such as inductors and high di/dt traces). Use a ground plane to shield the remote-sense traces from noise sources. To filter out common-mode noise, RC filtering is recommended for these inputs as shown in Figure 5. For VRD applications, a 100 Ω resistor with a 1nF capacitor should be used. For VRM applications, additional 50Ω resistors should be connected from these inputs to the local outputs of the converter before the VRM connector. This avoids excessive voltage at the CPU in case the remote-sense connections get disconnected.

Programming the Output-Voltage Droop Both the MAX8809A and MAX8810A employ peak-current-mode control with finite gain to actively set the output-voltage droop. Figure 6 shows the simplified control block diagram. The relationship between the output inductor current in an N-phase DC-DC converter and the output voltage of the voltage-error amplifier is:

$$
V_C = \frac{I_{OUT}}{N} \times R_{SENSE} \times G_{CA}
$$

where GCA (30V/V typ) is the gain of the differential current amplifier and N is the number of phases. I_{OUT} is the total output current. Therefore, when the output current increases, V_{C} increases. On the other hand, V_{C} is related to the output voltage of the converter by the following equation:

$$
V_C = g_{MV} \times R_{COMP} \times (V_{DAC} - V_{OUT})
$$

where g_{MV} is the transconductance of the voltage-error amplifier (2mS typ) and V_{DAC} is the VID-generated voltage.

Figure 6. Simplified Peak Current-Mode Control IC with Active Output-Voltage Positioning

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The DC gain of the voltage-error amplifier is equal to gMV x RCOMP. From the previous equations it is clear that the output-voltage droop can be accurately programmed if the DC gain of the voltage-error amplifier is set to be a finite value. As the output current increases, V_C increases and, consequently, V_{OUT} decreases. Define the output-droop resistance, RDROOP, as:

$$
R_{DROOP} = \frac{(V_{DAC} - V_{OUT})}{I_{OUT}}
$$

then R_{DROOP} can be expressed as:

$$
R_{DROOP} = \frac{R_{SENSE} \times G_{CA}}{N \times g_{MV} \times R_{COMP}}
$$

Since G_{CA} and G_{MV} are constants, R_{DROOP} is solely determined by RCOMP when RSENSE and N are chosen.

Peak current-mode control with finite gain is the simplest way to achieve the output-voltage droop without introducing a separate current loop, which is the case for voltage-mode control. Therefore, the response time of the output-voltage droop is the same as the voltagefeedback loop, resulting in fast output-voltage-droop transient response and less output capacitance than solutions using voltage-mode control.

Other features offered by peak-current-mode control are excellent line regulation and inherent current sharing between phases. Standard peak-current-mode control does have one disadvantage in that current matching between phases is impacted by the inductor mismatch (tolerance) between phases. Because only the current peak is controlled, any mismatch in the inductor value between two phases creates an inductor ripple current mismatch, which, in turn, creates a DC current mismatch between those two phases. Tolerance mismatch between the current-sense capacitors used in DCR current sensing creates the exact same DC current mismatch as an inductor mismatch.

Maxim's proprietary RA² technology addresses this issue by averaging out the inductor ripple current individually at each phase, as shown in Figure 7. The rapid active average circuitry learns the peak-to-peak ripple current of each phase in 5 to 10 switching cycles and then biases the peak current signal down by half of the peak-to-peak ripple current, consequently eliminating the impact of both output inductance and DCR currentsense capacitance variations. Since the rapid active

Figure 7. Implementation of the Rapid Active Averaging (RA²) **Algorithm**

average circuitry is not part of the current-loop path, it does not slow down the transient response.

Programming the Output Offset Voltage

According to the Intel VRD specifications, the output voltage at no load cannot exceed the voltage specified by the VID code, including the initial set tolerance, ripple voltage, and other errors. Therefore, the actual output voltage should be biased lower to compensate for these errors. For the MAX8809A, the output-voltage offset is created through a resistor-divider that is connected between REF and GND, with the center tap connected to COMP as shown in Figure 8. This resistordivider also sets the output load-line. The MAX8810A contains a BUF output that makes the output-voltage offset setting independent of the output load-line. To program the output-voltage offset, connect a resistor between COMP and GND. A resistor between BUF and COMP sets the output load-line. See the Loop Compensation Design section for details on setting the output-voltage offset.

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Figure 8. Programming the Output Offset Voltage

Load-Line Independent Inductor DC Resistance Temperature Compensation

Changes in inductor resistance due to temperature cause a change in the output-droop characteristic. This is compensated by changing the gain of the currentsense amplifier as a function of temperature. In doing so, the voltage at COMP is independent of temperature, resulting in a temperature-independent load-line setting. Additionally, the output short-circuit protection is also temperature independent because current limit is implemented by clamping the voltage at COMP. This technology uses an NTC thermistor solely for temperature compensation, freeing it from being one of the components that determines the output load-line. Therefore, only one NTC thermistor is needed to enable any output load-line. The same NTC thermistor is used for temperature sense for the VRHOT output. The MAX8809A/ MAX8810A temperature-compensation scheme is optimized for use with a Panasonic ERTJ1VR103 10kΩ NTC thermistor. Other thermistors may be used. Contact your local Maxim representative for more details.

Loop Compensation

During a load transient, the output voltage instantly changes due to the ESR of the output capacitors by an amount equal to their ESR times the change in load current $(\Delta V_{\text{OUT}} =$ R_{ESR} x $\Delta I_{\text{LOAD}})$. The output voltage then deviates further based on the speed at which the loop compensates for the load transient. The voltage-positioning method allows better utilization of the output regulation window, resulting in less required output capacitors. The RA2 architecture adjusts the output current based on the instantaneous output voltage, resulting in fast voltage positioning. The voltage-error amplifier consists of a high-bandwidth, high-accuracy transconductance amplifier (9_Mv) in Figure 7). The negative input of the transconductance amplifier is connected to the output of the remote-voltage differential amplifier, and the positive input is connected to the output of an internal DAC controlled by the VID inputs. The DC gain of the transconductance amplifier is set to a finite value to achieve fast output-voltage positioning by connecting an RC circuit (RCOMP and CCOMP) from COMP to GND. See the Loop-Compensation Design section for details on selecting the required components.

VR Ready Output (VRREADY)

VRREADY is an open-drain output that turns high impedance when the output voltage reaches regulation. VRREADY goes low if VOUT is less than (VDAC -225mV) or greater than (V_{DAC} + 175mV), signaling an out-of-regulation fault. VRREADY is held low in shutdown, if V_{CC} is less than the UVLO threshold, or during soft-start. For logic-level output voltages, connect an external pullup resistor between VRREADY and the logic power supply. A 100kΩ resistor works well in most applications.

Dynamic VID Change

The MAX8809A/MAX8810A provide the ability for the CPU to dynamically change the VID inputs while the controller is operating (on-the-fly or OTF). The output voltage changes in 6.25mV steps (Intel) or 12.5mV/25mV steps (AMD) when a VID change is detected.

The controller provides a 400ns logic-skew window to prevent false code changes. The controller accepts both step-by-step changes of VID inputs or all-at-once VID input changes. For all-at-once VID input changes, the output-voltage slew rate is the same, 1 LSB per step and 2µs duration. VRREADY is blanked during dynamic VID changes.

Multiphase Operation Selection

The MAX8809A operates in either a 2- or 3-phase configuration. Connect PWM3 to V_{CC} for 2-phase operation.

The MAX8810A operates in 2-, 3- or 4-phase configuration. Connect PWM4 to V_{CC} for 3-phase operation. Connect PWM4 and PWM3 to V_{CC} for 2-phase operation. All active PWM outputs are held low during shutdown.

UVLO and Output Enable

When the IC supply voltage (V_{CC}) is less than the UVLO threshold (4.25V typ), all active PWM outputs are internally pulled low and most internal circuitry is shut down to reduce the quiescent current. When EN is released and V_{CC} > UVLO, the internal 100kΩ resistor pulls EN to V_{CC} and soft-start is initiated (after a typical 2.2ms delay).

When the driver supply voltage (V_{VL}) is less than its UVLO threshold (3.55V typ), DH_ and DL_ are held low. If V_{V} is above the UVLO threshold and while EN is low, DL_ is driven high and DH_ is held low. This prevents the output of the converter from rising before a valid EN high signal is present.

Soft-Start The MAX8809A/MAX8810A soft-start with 6.25mV steps, regardless of processor architecture. Connect a resistor between SS/OVP and GND to program the softstart time. When the device is enabled, SS/OVP is driven to 2V and the current drawn by the set resistor is measured. This current sets the internal delay time between the DAC voltage steps. Select a resistor between 12kΩ and 90.9kΩ for a corresponding soft-

Table 1. Intel Startup Sequence Specifications

start time of 500µs to 6.5ms. For Intel designs, the resistor value is calculated as:

$$
R_{SS/OVP}(kΩ) = \frac{t_{SS} - 0.0183}{0.0532}
$$

where tss is the desired soft-start time (in ms) to the 1.1V VBOOT level. Figure 9 shows the Intel startup sequence, and Table 1 shows the values of the time delays.

For AMD applications, the controllers soft-start up to the voltage set by the VID inputs. The soft-start time is set by the following equation:

$$
R_{SS/OVP}(kΩ) = \frac{t_{SS} - 0.0183}{0.0532} \times \frac{1.1V}{V_{DAC}}
$$

where V_{DAC} is the output voltage set by the VID inputs. Figure 10 shows the AMD startup sequence, and Table 2 shows the values of the time delays.

Soft-Stop

MAX8809A/MAX8810A

A01887AM/A2887AM

When EN goes low, the output of the converter ramps down to 0V in 6.25mV DAC steps in the time set by the SS/OVP input. Once the output reaches 0V, DL is held high and DH is held low to maintain the 0V output. This

Figure 9. Intel VRD11/VRD10 Startup Sequence

Figure 10. K8 Rev F Startup Sequencing and Timing

Table 2. AMD Startup Sequence Specifications

*User programmable.

approach prevents large negative voltages on the output during shutdown and therefore eliminates the need for a Schottky clamp diode on the output.

Output Overvoltage Protection (OVP)

When the output voltage exceeds the regulation voltage by 200mV (Intel) or exceeds 1.8V (AMD), all active PWM outputs are pulled low and the controller is latched off. SS/OVP is internally pulled to V_{CC} to signal an overvoltage fault. All DH outputs are held low and all DL outputs are held high to discharge the output. The latch condition can only be cleared by cycling the input voltage (V_{CC}).

Integrated Dual-MOSFET Driver

The MAX8809A/MAX8810A contain a dual-phase gate driver capable of driving 3000pF capacitive loads with only 32ns propagation delay and 11ns typical rise and fall times, allowing operation up to 1.2MHz per phase. Adaptive dead time controls low-side MOSFET turn-on and high-side MOSFET turn-on. This maximizes converter efficiency, while allowing operation with a variety of MOSFETs. A UVLO circuit ensures proper power-on sequencing.

Adaptive Shoot-Through Protection

Adaptive shoot-through protection is incorporated for the switching transition after the high-side MOSFET is turned off and before the low-side MOSFET is turned on. The low-side driver is turned on only when the LX_ voltage falls below 2.5V typical. In addition, a fixed 35ns delay time between the low-side MOSFET turn-off and high-side MOSFET turn-on adds further protection from "shoot-through." The 35ns time begins after DL_ has fallen through 1.5V typical.

MOSFET Driver UVLO

When V_{VL12} (MAX8809A) or V_{VL1} (MAX8810A) is below the UVLO threshold (3.55 typ), DH_ and DL_ are held

low. Once VVL_ is above the UVLO threshold and EN is low, DL_ is kept high and DH_ is kept low. This prevents the output from rising before a valid EN signal is given.

Boost Circuit for High-Side MOSFET Driver

The gate-drive voltage for the high-side MOSFET drivers is generated by a flying-capacitor boost circuit. The capacitor between BST_ and LX_ is charged from the VL_ supply through an internal switch while the lowside MOSFET is on. When the low-side MOSFET is switched off, the stored voltage on the capacitor is stacked above LX_ to provide the necessary turn-on voltage for the high-side MOSFET(s). No external boost diode is needed. See the Boost Capacitor Selection section for details on selecting the correct capacitor.

Thermal Protection

The MAX8809A/MAX8810A feature a thermal-fault-protection circuit. When the junction temperature rises above +160°C typical, an internal thermal sensor activates the shutdown circuit to hold all MOSFET drivers and active PWM outputs low to disable switching. The thermal sensor reactivates the controller after the junction temperature cools by 25°C typical.

Temperature Monitoring (VRTSET, VRHOT)

The MAX8809A/MAX8810A contain temperature-monitoring circuitry that allows the user to program a temperature trip point between +60°C and +125°C, and

Table 3. Temperature Scale Factor

monitor an active-high, open-drain VRHOT output. Connect a resistor from VRTSET to GND to set the temperature-monitoring threshold. The resistor is calculated as follows:

$$
R_{\text{VRTSET}} = \frac{800}{0.6K_{\text{T}}} \text{ in } k\Omega
$$

where K_T is a temperature scale factor specifically for the Panasonic ERTJ1VR103 NTC thermistor. Table 3 provides values of K_T and the closest standard 1% RVRTSET values needed to program the VRHOT threshold over a +60°C to +125°C range. RVRTSET must be greater than 20kΩ. Contact your local Maxim representative for information on using other thermistors.

Architecture Selection and Timing

AMD K8 Rev F

The AMD K8 Rev F processor uses a 6-bit VID code that specifies a 0.375V to 1.55V output voltage range (see Table 4). Leave SEL unconnected to select the AMD K8 Rev F architecture. The startup sequencing and timing specifications are shown in Figure 10. Note that the VID input defines the AMD processor boot level, and there is no internal default. The boot level is not latched; therefore, if the codes change during softstart, the boot level also changes.

Extended Intel VRD10

The Intel VRD10 processor uses a 7-bit VID code that specifies a 0.83125V to 1.6V output voltage range (see Table 5). Connect SEL to GND to select the VRD10 architecture. The startup sequencing and timing specifications are shown in Figure 9. The Intel boot level is internally set to 1.1V; therefore, the VID inputs are ignored during soft-start. In compliance with the Intel VRD specifications, there is a typical 2.2ms delay after EN is asserted before soft-start begins. This delay is not included in the soft-start time set by SS/OVP.

Intel VRD11

The Intel VRD11 processor uses an 8-bit VID code that specifies a 0.3125V to 1.6V output voltage range (see Table 6). Connect SEL to V_{CC} to select the VRD11 architecture. The startup sequencing and timing specifications are shown in Figure 9. The Intel boot level is internally set to 1.1V; therefore, the VID inputs are ignored during soft-start. In compliance with the Intel VRD specifications, there is a typical 2.2ms delay after EN is asserted before soft-start begins. This delay is not included in the soft-start time set by SS/OVP.